

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7240	(third adj (electrode or gate)).clm.	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:36
L2	2115	1 and (different near10 (metal or conduct\$3 or electrode or gate))	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:36
L3	2289	1 and (different near10 (metal or conduct\$3 or electrode or gate or material))	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:36
L4	562	3 and (transistor\$1.clm.)	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:37
L5	316	4 and (MOSTFT\$1 or MOS or TFT\$1)	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:38
L6	316	5 and (gate or electrode)	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:38
L7	265	6 and (insulat\$3 or dielectric)	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:39
L8	150	7 and (LDD or (p adj channel) or (n adj channel))	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:40
L9	134	8 and (doping or implant\$3 or impurit\$4)	US-PGPUB; USPAT	OR	OFF	2005/03/31 07:43
L10	28	9 and ((plurality or third) adj transistor\$1).clm.	US-PGPUB; USPAT	OR	OFF	2005/03/31 08:08
L11	3	(("20040179144") or ("20020182756") or ("6046484")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/31 08:08